

## INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## **IRFR7746, IIRFR7746**



- Static drain-source on-resistance: RDs(on)≤11.2mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

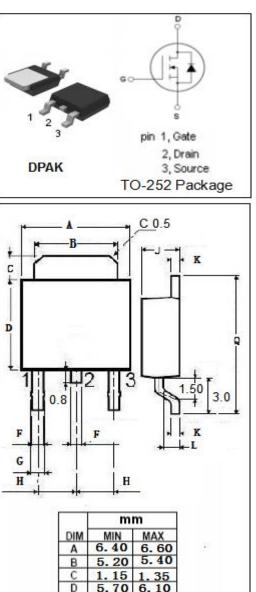
Synchronous rectifier applications

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C

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SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	75	V				
$V_{GS}$	Gate-Source Voltage	±20	V				
ID	Drain Current-Continuous	42	А				
I <sub>DM</sub>	Drain Current-Single Pulsed	230	А				
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	99	W				
Tj	Max. Operating Junction Temperature	175	°C				
T <sub>stg</sub>	Storage Temperature	-55~175	°C				

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
Rth(j-c)	Channel-to-case thermal resistance	1.52	°C <b>/W</b>	
Rth(j-a)	Rth(j-a) Channel-to-ambient thermal resistance		°C/W	



0.68

2.10

0.40

0.90

50

40

0.60

10

Н

K

0



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### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	75			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =100 µ A	2.1		3.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =35A			11.2	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20V$			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =75V; V <sub>GS</sub> = 0V			1	μA
V <sub>SD</sub>	Diode forward voltage	I <sub>s</sub> =35A, V <sub>GS</sub> = 0V			1.2	V

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